

Description

The 74AHCT00 provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

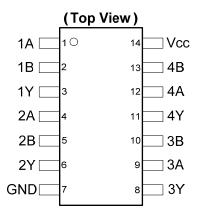
The gates perform the Boolean function:

$$Y = \overline{A \bullet B}$$
 or $Y = \overline{A} + \overline{B}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

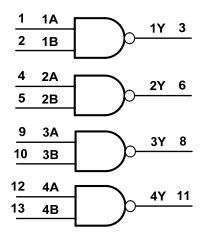
Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O < 0V	-20	mA
lok	Output Clamp Current Vo > Vcc	20	mA
Io	Continuous Output Current 0V < V _O < V _{CC}	+/- 25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate		20	ns/V
T _A	Operating Free-Air Temperature	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Comple of	Domonoston	Took Conditions	Test Conditions		T _A = -40°C to +85°C		T _A = -40°C to +125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V
V _{IL}	Low-Level Input voltage		4.5V to 5.5V		0.8		0.8	V
1/	High-Level	I _{OH} = -50μA	4.5V	4.4		4.4		V
V _{OH}	Output Voltage	I _{OH} = -8mA	4.5V	3.80		3.70		ľ
\ /	Low-Level	I _{OL} = 50μA	4.5V		0.1		0.1	V
V_{OL}	Output Voltage	I _{OL} = 8mA	4.5V		0.44		0.55	\ \
II	Input Current	V _I =GND to 5.5V	3.6V		±1		±2	μA
I _{CC}	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μΑ
ΔI _{CC}	Additional Supply Current	One input at V _{CC} -2.1V Other pins at V _{CC} or GND	5.5V		1.35		5	mA

Operating Characteristics

	Parameter	Test Conditions	V _{CC} = 5.5V Typ	Unit
$C_{\sf pd}$	Power dissipation capacitance per gate	f = 1MHz	14.8	pF
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	4.0	pF

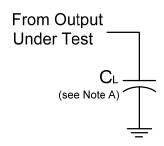
Switching Characteristics

Symbol	Parameter	Test	V	7	Γ _A = +25°0	;	-40°C to	+85°C	-40°C to	+125°C	Unit
Symbol	raiailletei	Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Ollit
	Propagation Delay	Figure 1 $C_L = 15pF$	4.5V to 5.5V	0.5	3.4	6.9	0.5	8.0	0.5	9.0	no
t _{PD}	A_N to Y_N	Figure 1 $C_L = 50pF$	4.5V to 5.5V	0.5	4.9	10.0	0.5	10.0	0.5	11.0	ns

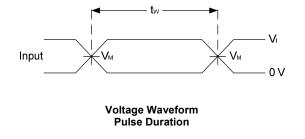
^{5.} Unused inputs should be held at V_{CC} or Ground.

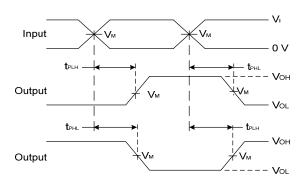


Parameter Measurement Information



V	Inputs		V _M	V _M	
V _{CC}	VI	t _r /t _f	Inputs	Outputs	C _L
4.5V to 5.5V	3.0 V	3ns	1.5 V	V _{CC} /2	15pF, 50pF





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

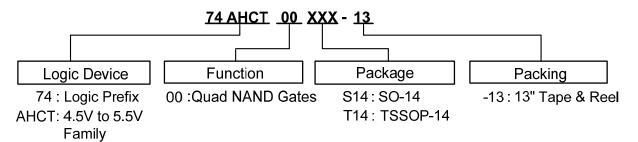
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$



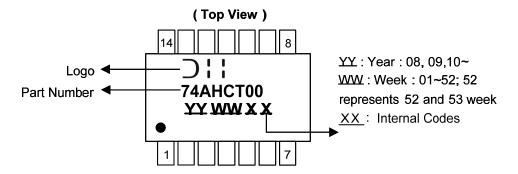
Ordering Information



Part Number	Package Code	Dockoning	7" Tape	and Reel
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHCT00S14-13	S14	SO-14	2500/Tape & Reel	-13
74AHCT00T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14



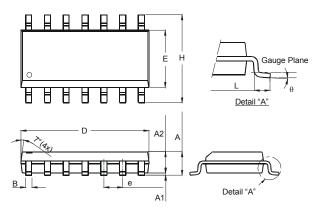
Part Number	Package
74AHCT00S14	SO-14
74AHCT00T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

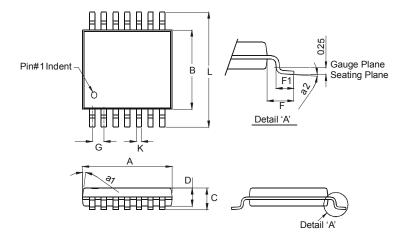
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Din	nensions	All Dimensions in mm			

Package Type: TSSOP-14



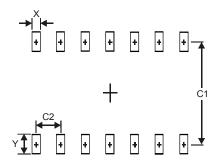
TSSOP-14				
Dim	Min	Max		
a1	7° (4	IX)		
a2	0°	8°		
Α	4.9	5.10		
В	4.30	4.50		
С		1.2		
D	8.0	1.05		
F	1.00	Тур		
F1	0.45	0.75		
G	0.65	Тур		
K	0.19 0.30			
L 6.40 Typ				
All Dimensions in				
mm				



Suggested Pad Layout

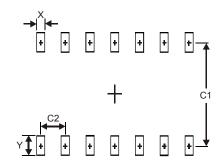
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimension	Value (in
s	mm)
X	0.60
Υ	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimension	Value (in
S	mm)
Χ	0.45
Υ	1.45
C1	5.9
C2	0.65



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